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Details

Product Status	Active
Core Processor	e200z0h
Core Size	32-Bit Single-Core
Speed	64MHz
Connectivity	CANbus, LINbus, SCI, SPI
Peripherals	DMA, POR, PWM, WDT
Number of I/O	45
Program Memory Size	256KB (256K x 8)
Program Memory Type	FLASH
EEPROM Size	4K x 16
RAM Size	20K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 16x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/spc5602pef0vlh6

1 Introduction

1.1 Document overview

This document provides electrical specifications, pin assignments, and package diagrams for the MPC5601P/2P series of microcontroller units (MCUs). It also describes the device features and highlights important electrical and physical characteristics. For functional characteristics, refer to the device reference manual.

1.2 Description

This 32-bit system-on-chip (SoC) automotive microcontroller family is the latest achievement in integrated automotive application controllers. It belongs to an expanding range of automotive-focused products designed to address chassis applications—specifically, electrical hydraulic power steering (EHPS) and electric power steering (EPS)—as well as airbag applications.

This family is one of a series of next-generation integrated automotive microcontrollers based on the Power Architecture® technology.

The advanced and cost-efficient host processor core of this automotive controller family complies with the Power Architecture embedded category. It operates at speeds of up to 64 MHz and offers high performance processing optimized for low power consumption. It capitalizes on the available development infrastructure of current Power Architecture devices and is supported with software drivers, operating systems and configuration code to assist with users implementations.

1.3 Device comparison

Table 1 provides a summary of different members of the MPC5602P family and their features to enable a comparison among the family members and an understanding of the range of functionality offered within this family.

Table 1. MPC5602P device comparison

Feature	MPC5601P	MPC5602P
Code flash memory (with ECC)	192 KB	256 KB
Data flash memory / EE option (with ECC)	64 KB (optional feature)	
SRAM (with ECC)	12 KB	20 KB
Processor core	32-bit e200z0h	
Instruction set	VLE (variable length encoding)	
CPU performance	0–64 MHz	
FMPLL (frequency-modulated phase-locked loop) module	1	
INTC (interrupt controller) channels	120	
PIT (periodic interrupt timer)	1 (with four 32-bit timers)	
eDMA (enhanced direct memory access) channels	16	
FlexCAN (controller area network)	1 ^{1,2}	2 ^{1,2}
Safety port	Yes (via FlexCAN module)	Yes (via second FlexCAN module)
FCU (fault collection unit)	Yes	
CTU (cross triggering unit)	No	Yes
eTimer	1 (16-bit, 6 channels)	

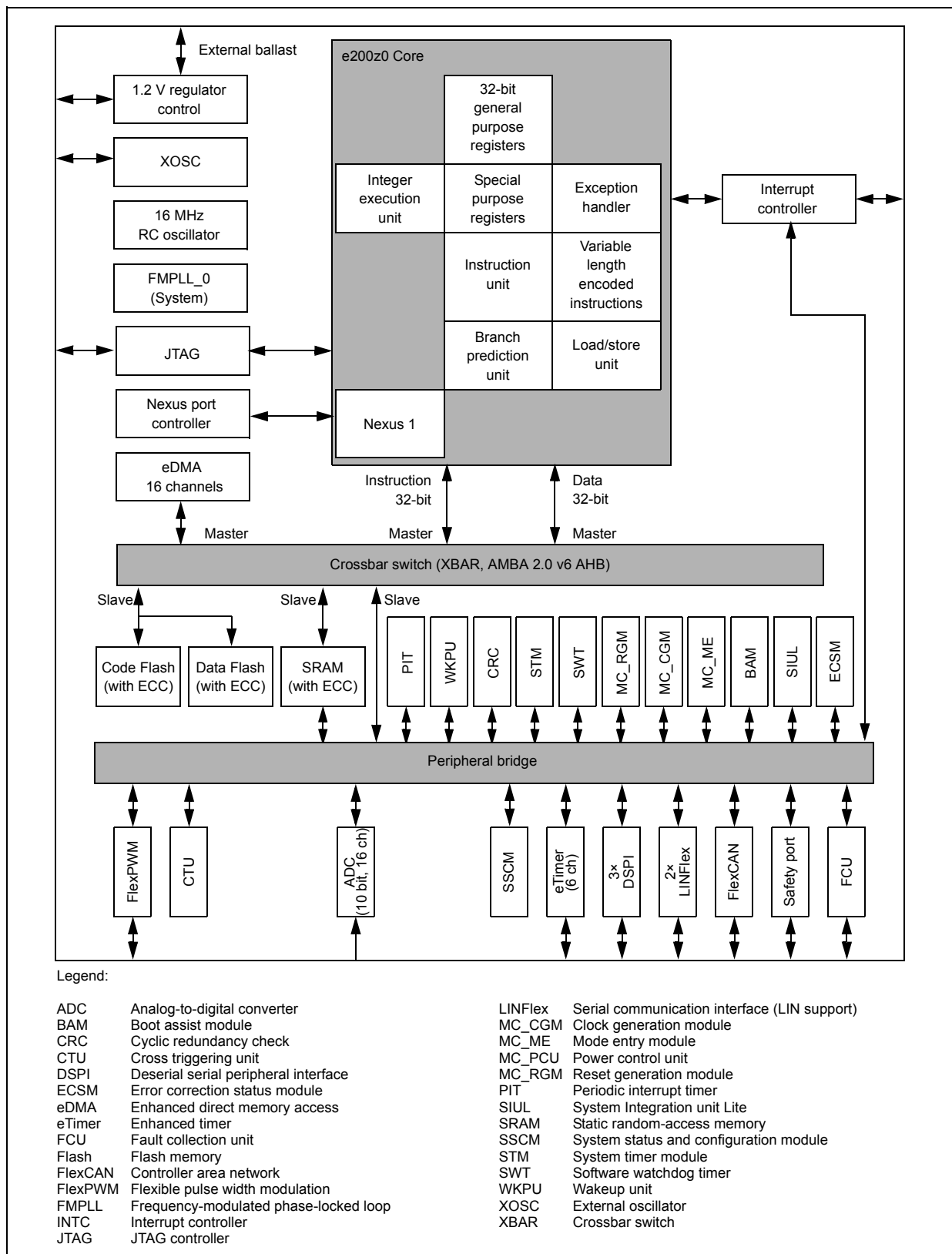


Figure 1. MPC5602P block diagram

- Clock frequency same as that used for e200z0h core
- PWM outputs can operate as complementary pairs or independent channels
- Can accept signed numbers for PWM generation
- Independent control of both edges of each PWM output
- Synchronization to external hardware or other PWM supported
- Double buffered PWM registers
 - Integral reload rates from 1 to 16
 - Half cycle reload capability
- Multiple ADC trigger events can be generated per PWM cycle via hardware
- Write protection for critical registers
- Fault inputs can be assigned to control multiple PWM outputs
- Programmable filters for fault inputs
- Independently programmable PWM output polarity
- Independent top and bottom deadtime insertion
- Each complementary pair can operate with its own PWM frequency and deadtime values
- Individual software-control for each PWM output
- All outputs can be programmed to change simultaneously via a “Force Out” event
- PWMX pin can optionally output a third PWM signal from each submodule
- Channels not used for PWM generation can be used for buffered output compare functions
- Channels not used for PWM generation can be used for input capture functions
- Enhanced dual-edge capture functionality
- eDMA support with automatic reload
- 2 fault inputs
- Capture capability for PWMA, PWMB, and PWMX channels not supported

1.5.25 eTimer

The MPC5602P includes one eTimer module which provides six 16-bit general purpose up/down timer/counter units with the following features:

- Clock frequency same as that used for the e200z0h core
- Individual channel capability
 - Input capture trigger
 - Output compare
 - Double buffer (to capture rising edge and falling edge)
 - Separate prescaler for each counter
 - Selectable clock source
 - 0–100% pulse measurement
 - Rotation direction flag (quad decoder mode)
- Maximum count rate
 - External event counting: max. count rate = peripheral clock/2
 - Internal clock counting: max. count rate = peripheral clock
- Counters are:
 - Cascadable
 - Preloadable
- Programmable count modulo
- Quadrature decode capabilities

- ACCESS_AUX_TAP_ONCE
- 3 test data registers:
 - Bypass register
 - Boundary scan register (size parameterized to support a variety of boundary scan chain lengths)
 - Device identification register
- TAP controller state machine that controls the operation of the data registers, instruction register and associated circuitry

1.5.31 On-chip voltage regulator (VREG)

The on-chip voltage regulator module provides the following features:

- Uses external NPN (negative-positive-negative) transistor
- Regulates external 3.3 V/5.0 V down to 1.2 V for the core logic
- Low voltage detection on the internal 1.2 V and I/O voltage 3.3 V

2 Package pinouts and signal descriptions

2.1 Package pinouts

The LQFP pinouts are shown in the following figures. For pin signal descriptions, please refer to [Table 5](#).

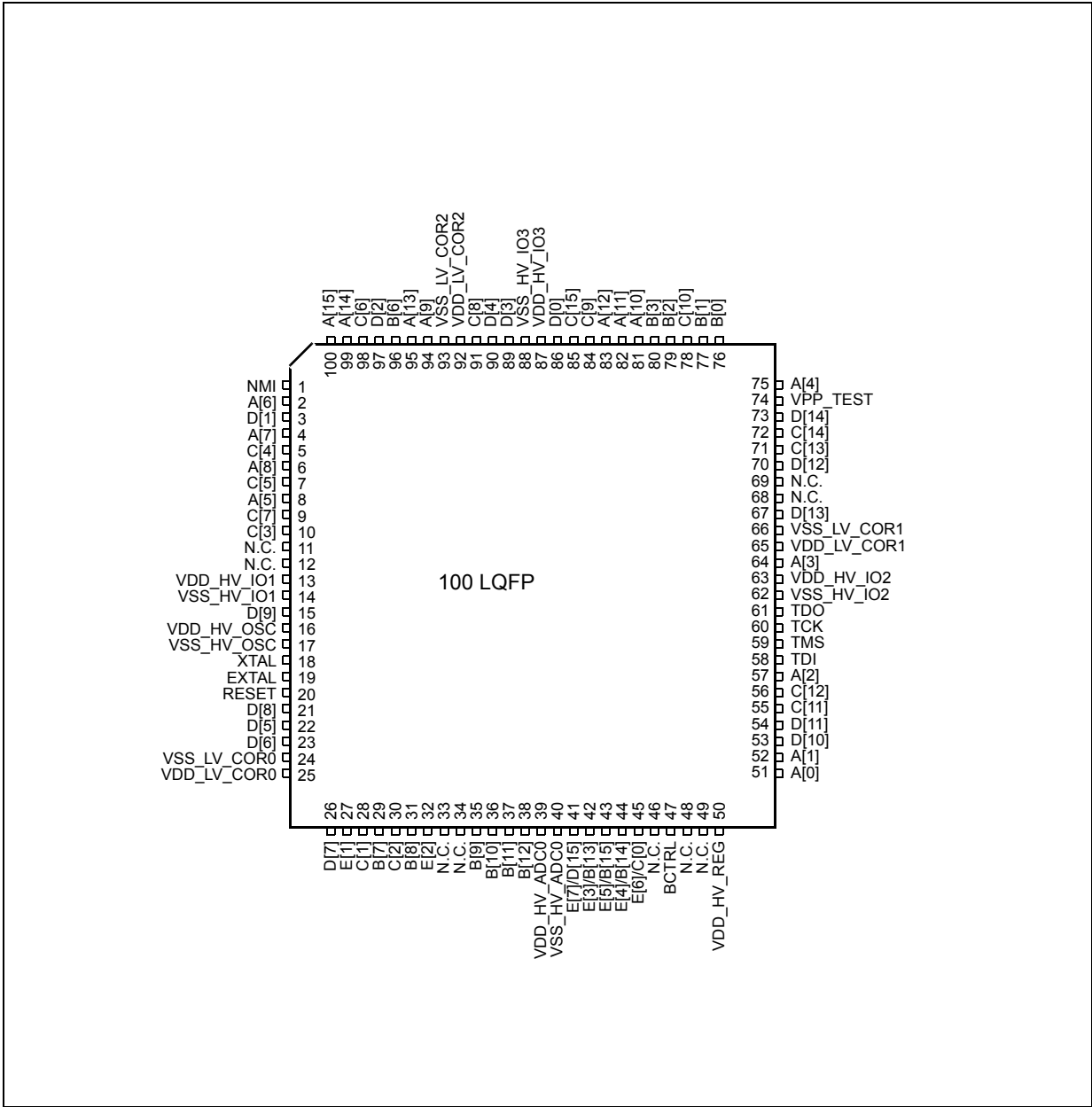


Figure 3. 100-pin LQFP pinout (top view)

2.2 Pin description

The following sections provide signal descriptions and related information about the functionality and configuration of the MPC5602P devices.

2.2.1 Power supply and reference voltage pins

Table 3 lists the power supply and reference voltage for the MPC5602P devices.

2.2.2 System pins

Table 4 and Table 5 contain information on pin functions for the MPC5602P devices. The pins listed in Table 4 are single-function pins. The pins shown in Table 5 are multi-function pins, programmable via their respective pad configuration register (PCR) values.

Table 4. System pins

Symbol	Description	Direction	Pad speed ¹		Pin	
			SRC = 0	SRC = 1	64-pin	100-pin
Dedicated pins						
NMI	Non-maskable Interrupt	Input only	Slow	—	1	1
XTAL	Analog output of the oscillator amplifier circuit—needs to be grounded if oscillator is used in bypass mode	—	—	—	11	18
EXTAL	Analog input of the oscillator amplifier circuit, when the oscillator is not in bypass mode Analog input for the clock generator when the oscillator is in bypass mode	—	—	—	12	19
TDI	JTAG test data input	Input only	Slow	—	35	58
TMS	JTAG state machine control	Input only	Slow	—	36	59
TCK	JTAG clock	Input only	Slow	—	37	60
TDO	JTAG test data output	Output only	Slow	Fast	38	61
Reset pin						
$\overline{\text{RESET}}$	Bidirectional reset with Schmitt trigger characteristics and noise filter	Bidirectional	Medium	—	13	20
Test pin						
VPP_TEST	Pin for testing purpose only. To be tied to ground in normal operating mode.	—	—	—	47	74

¹ SRC values refer to the value assigned to the Slew Rate Control bits of the pad configuration register.

2.2.3 Pin multiplexing

Table 5 defines the pin list and muxing for the MPC5602P devices.

Each row of Table 5 shows all the possible ways of configuring each pin, via alternate functions. The default function assigned to each pin after reset is the ALT0 function.

MPC5602P devices provide three main I/O pad types, depending on the associated functions:

- *Slow pads* are the most common, providing a compromise between transition time and low electromagnetic emission.
- *Medium pads* provide fast enough transition for serial communication channels with controlled current to reduce electromagnetic emission.
- *Fast pads* provide maximum speed. They are used for improved NEXUS debugging capability.

Medium and Fast pads can use slow configuration to reduce electromagnetic emission, at the cost of reducing AC performance. For more information, see “Pad AC Specifications” in the device data sheet.

Table 5. Pin muxing (continued)

Port pin	PCR register	Alternate function ^{1,2}	Functions	Peripheral ³	I/O direction ⁴	Pad speed ⁵		Pin	
						SRC = 0	SRC = 1	64-pin	100-pin
A[8]	PCR[8]	ALT0 ALT1 ALT2 ALT3 — —	GPIO[8] — — — SIN EIRQ[8]	SIUL — — — DSPI_1 SIUL	I/O — — — I I	Slow	Medium	4	6
A[9]	PCR[9]	ALT0 ALT1 ALT2 ALT3 —	GPIO[9] CS1 — B[3] FAULT[0]	SIUL DSPI_2 — FlexPWM_0 FlexPWM_0	I/O O — O I	Slow	Medium	60	94
A[10]	PCR[10]	ALT0 ALT1 ALT2 ALT3 —	GPIO[10] CS0 B[0] X[2] EIRQ[9]	SIUL DSPI_2 FlexPWM_0 FlexPWM_0 SIUL	I/O I/O O O I	Slow	Medium	52	81
A[11]	PCR[11]	ALT0 ALT1 ALT2 ALT3 —	GPIO[11] SCK A[0] A[2] EIRQ[10]	SIUL DSPI_2 FlexPWM_0 FlexPWM_0 SIUL	I/O I/O O O I	Slow	Medium	53	82
A[12]	PCR[12]	ALT0 ALT1 ALT2 ALT3 —	GPIO[12] SOUT A[2] B[2] EIRQ[11]	SIUL DSPI_2 FlexPWM_0 FlexPWM_0 SIUL	I/O O O O I	Slow	Medium	54	83
A[13]	PCR[13]	ALT0 ALT1 ALT2 ALT3 — — —	GPIO[13] — B[2] — SIN FAULT[0] EIRQ[12]	SIUL — FlexPWM_0 — DSPI_2 FlexPWM_0 SIUL	I/O — O — I I I I	Slow	Medium	61	95
A[14]	PCR[14]	ALT0 ALT1 ALT2 ALT3 —	GPIO[14] TXD — — EIRQ[13]	SIUL Safety Port_0 — — SIUL	I/O O — — I	Slow	Medium	63	99
A[15]	PCR[15]	ALT0 ALT1 ALT2 ALT3 — —	GPIO[15] — — — RXD EIRQ[14]	SIUL — — — Safety Port_0 SIUL	I/O — — — I I	Slow	Medium	64	100

Table 5. Pin muxing (continued)

Port pin	PCR register	Alternate function ^{1,2}	Functions	Peripheral ³	I/O direction ⁴	Pad speed ⁵		Pin	
						SRC = 0	SRC = 1	64-pin	100-pin
D[4]	PCR[52]	ALT0 ALT1 ALT2 ALT3	GPIO[52] — — B[3]	SIUL — — FlexPWM_0	I/O — — O	Slow	Medium	—	90
D[5]	PCR[53]	ALT0 ALT1 ALT2 ALT3	GPIO[53] CS3 F[0] —	SIUL DSPI_0 FCU_0 —	I/O O O —	Slow	Medium	—	22
D[6]	PCR[54]	ALT0 ALT1 ALT2 ALT3 —	GPIO[54] CS2 — — FAULT[1]	SIUL DSPI_0 — — FlexPWM_0	I/O O — — I	Slow	Medium	—	23
D[7]	PCR[55]	ALT0 ALT1 ALT2 ALT3	GPIO[55] CS3 F[1] CS4	SIUL DSPI_1 FCU_0 DSPI_0	I/O O O O	Slow	Medium	17	26
D[8]	PCR[56]	ALT0 ALT1 ALT2 ALT3	GPIO[56] CS2 — CS5	SIUL DSPI_1 — DSPI_0	I/O O — O	Slow	Medium	14	21
D[9]	PCR[57]	ALT0 ALT1 ALT2 ALT3	GPIO[57] X[0] TXD —	SIUL FlexPWM_0 LIN_1 —	I/O O O —	Slow	Medium	8	15
D[10]	PCR[58]	ALT0 ALT1 ALT2 ALT3	GPIO[58] A[0] — —	SIUL FlexPWM_0 — —	I/O O — —	Slow	Medium	—	53
D[11]	PCR[59]	ALT0 ALT1 ALT2 ALT3	GPIO[59] B[0] — —	SIUL FlexPWM_0 — —	I/O O — —	Slow	Medium	—	54
D[12]	PCR[60]	ALT0 ALT1 ALT2 ALT3 —	GPIO[60] X[1] — — RXD	SIUL FlexPWM_0 — — LIN_1	I/O O — — I	Slow	Medium	45	70
D[13]	PCR[61]	ALT0 ALT1 ALT2 ALT3	GPIO[61] A[1] — —	SIUL FlexPWM_0 — —	I/O O — —	Slow	Medium	44	67
D[14]	PCR[62]	ALT0 ALT1 ALT2 ALT3	GPIO[62] B[1] — —	SIUL FlexPWM_0 — —	I/O O — —	Slow	Medium	46	73

Table 5. Pin muxing (continued)

Port pin	PCR register	Alternate function ^{1,2}	Functions	Peripheral ³	I/O direction ⁴	Pad speed ⁵		Pin	
						SRC = 0	SRC = 1	64-pin	100-pin
D[15]	PCR[63]	ALT0 ALT1 ALT2 ALT3 — —	GPIO[63] — — — AN[10] emu. AN[4]	SIUL — — — ADC_0 emu. ADC_1 ⁶	Input only	—	—	—	41
Port E (16-bit)									
E[1]	PCR[65]	ALT0 ALT1 ALT2 ALT3 —	GPIO[65] — — — AN[4]	SIUL — — — ADC_0	Input only	—	—	18	27
E[2]	PCR[66]	ALT0 ALT1 ALT2 ALT3 —	GPIO[66] — — — AN[5]	SIUL — — — ADC_0	Input only	—	—	23	32
E[3]	PCR[67]	ALT0 ALT1 ALT2 ALT3 —	GPIO[67] — — — AN[6]	SIUL — — — ADC_0	Input only	—	—	30	42
E[4]	PCR[68]	ALT0 ALT1 ALT2 ALT3 —	GPIO[68] — — — AN[7]	SIUL — — — ADC_0	Input only	—	—	—	44
E[5]	PCR[69]	ALT0 ALT1 ALT2 ALT3 —	GPIO[69] — — — AN[8]	SIUL — — — ADC_0	Input only	—	—	—	43
E[6]	PCR[70]	ALT0 ALT1 ALT2 ALT3 —	GPIO[70] — — — AN[9]	SIUL — — — ADC_0	Input only	—	—	—	45
E[7]	PCR[71]	ALT0 ALT1 ALT2 ALT3 —	GPIO[71] — — — AN[10]	SIUL — — — ADC_0	Input only	—	—	—	41

¹ ALT0 is the primary (default) function for each port after reset.

- ¹ Functional operating conditions are given in the DC electrical characteristics. Absolute maximum ratings are stress ratings only, and functional operation at the maxima is not guaranteed. Stress beyond the listed maxima may affect device reliability or cause permanent damage to the device.
- ² The difference between each couple of voltage supplies must be less than 300 mV,
 $|V_{DD_HV_IOy} - V_{DD_HV_IOx}| < 300 \text{ mV}$.
- ³ Guaranteed by device validation.
- ⁴ Minimum value of TV_{DD} must be guaranteed until $V_{DD_HV_REG}$ reaches 2.6 V (maximum value of V_{PORH})
- ⁵ Only when $V_{DD_HV_IOx} < 5.2 \text{ V}$

Figure 4 shows the constraints of the different power supplies.

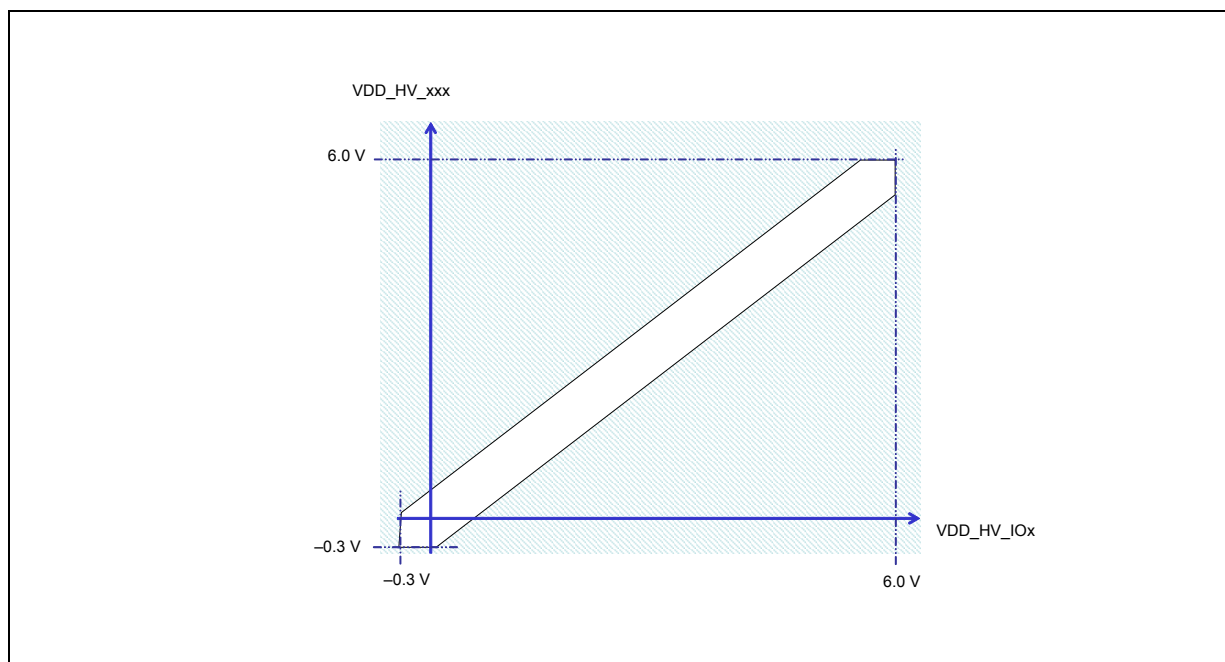


Figure 4. Power supplies constraints ($-0.3 \text{ V} \leq V_{DD_HV_IOx} \leq 6.0 \text{ V}$)

The MPC5602P supply architecture allows the ADC supply to be managed independently from the standard V_{DD_HV} supply. Figure 5 shows the constraints of the ADC power supply.

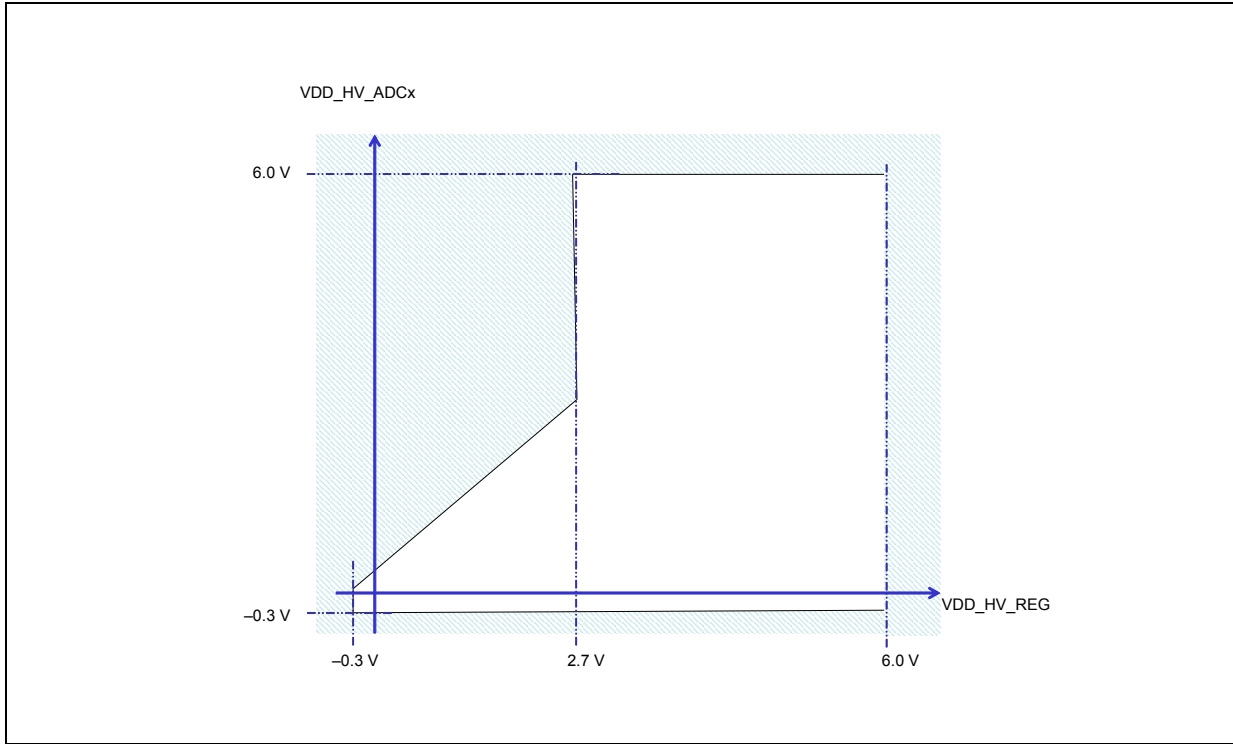


Figure 5. Independent ADC supply ($-0.3 \text{ V} \leq V_{DD_HV_REG} \leq 6.0 \text{ V}$)

3.4 Recommended operating conditions

Table 8. Recommended operating conditions (5.0 V)

Symbol	Parameter	Conditions	Value		Unit
			Min	Max ¹	
V_{SS}	SR	Device ground	—	—	V
$V_{DD_HV_IOx}^2$	SR	5.0 V input/output supply voltage	—	—	V
$V_{SS_HV_IOx}$	SR	Input/output ground voltage	—	—	V
$V_{DD_HV_OSC}$	SR	5.0 V crystal oscillator amplifier supply voltage	—	—	V
		Relative to $V_{DD_HV_IOx}$	$V_{DD_HV_IOx} - 0.1$	$V_{DD_HV_IOx} + 0.1$	
$V_{SS_HV_OSC}$	SR	5.0 V crystal oscillator amplifier reference voltage	—	—	V
$V_{DD_HV_REG}$	SR	5.0 V voltage regulator supply voltage	—	—	V
		Relative to $V_{DD_HV_IOx}$	$V_{DD_HV_IOx} - 0.1$	$V_{DD_HV_IOx} + 0.1$	
$V_{DD_HV_ADC0}$	SR	5.0 V ADC_0 supply and high reference voltage	—	—	V
		Relative to $V_{DD_HV_REG}$	$V_{DD_HV_REG} - 0.1$	—	

where:

$R_{\theta JA}$ = junction-to-ambient thermal resistance ($^{\circ}\text{C}/\text{W}$)

$R_{\theta JC}$ = junction-to-case thermal resistance ($^{\circ}\text{C}/\text{W}$)

$R_{\theta CA}$ = case-to-ambient thermal resistance ($^{\circ}\text{C}/\text{W}$)

$R_{\theta JC}$ is device related and cannot be influenced by the user. The user controls the thermal environment to change the case-to-ambient thermal resistance, $R_{\theta CA}$. For instance, the user can change the size of the heat sink, the air flow around the device, the interface material, the mounting arrangement on printed circuit board, or change the thermal dissipation on the printed circuit board surrounding the device.

To determine the junction temperature of the device in the application when heat sinks are not used, the Thermal Characterization Parameter (Ψ_{JT}) can be used to determine the junction temperature with a measurement of the temperature at the top center of the package case using Equation 3:

$$T_J = T_T + (\Psi_{JT} \times P_D) \quad \text{Eqn. 3}$$

where:

T_T = thermocouple temperature on top of the package ($^{\circ}\text{C}$)

Ψ_{JT} = thermal characterization parameter ($^{\circ}\text{C}/\text{W}$)

P_D = power dissipation in the package (W)

The thermal characterization parameter is measured per JESD51-2 specification using a 40 gauge type T thermocouple epoxied to the top center of the package case. The thermocouple should be positioned so that the thermocouple junction rests on the package. A small amount of epoxy is placed over the thermocouple junction and over about 1 mm of wire extending from the junction. The thermocouple wire is placed flat against the package case to avoid measurement errors caused by cooling effects of the thermocouple wire.

References:

- Semiconductor Equipment and Materials International
3081 Zanker Road
San Jose, CA 95134 U.S.A.
(408) 943-6900
- MIL-SPEC and EIA/JESD (JEDEC) specifications are available from Global Engineering Documents at (800) 854-7179 or (303) 397-7956.
- JEDEC specifications are available on the WEB at <http://www.jedec.org>.
- C.E. Triplett and B. Joiner, *An Experimental Characterization of a 272 PBGA Within an Automotive Engine Controller Module*, Proceedings of SemiTherm, San Diego, 1998, pp. 47–54.
- G. Kromann, S. Shidore, and S. Addison, *Thermal Modeling of a PBGA for Air-Cooled Applications*, Electronic Packaging and Production, pp. 53–58, March 1998.
- B. Joiner and V. Adams, *Measurement and Simulation of Junction to Board Thermal Resistance and Its Application in Thermal Modeling*, Proceedings of SemiTherm, San Diego, 1999, pp. 212–220.

- LVDLVCOR monitors low voltage digital power domain

Table 15. Low voltage monitor electrical characteristics

Symbol	C	Parameter	Conditions ¹	Value		Unit
				Min	Max	
V _{PORH}	T	Power-on reset threshold	—	1.5	2.7	V
V _{PORUP}	P	Supply for functional POR module	T _A = 25 °C	1.0	—	V
V _{REGLVDMOK_H}	P	Regulator low voltage detector high threshold	—	—	2.95	V
V _{REGLVDMOK_L}	P	Regulator low voltage detector low threshold	—	2.6	—	V
V _{FLLVDMOK_H}	P	Flash low voltage detector high threshold	—	—	2.95	V
V _{FLLVDMOK_L}	P	Flash low voltage detector low threshold	—	2.6	—	V
V _{IOLVDMOK_H}	P	I/O low voltage detector high threshold	—	—	2.95	V
V _{IOLVDMOK_L}	P	I/O low voltage detector low threshold	—	2.6	—	V
V _{IOLVDM5OK_H}	P	I/O 5 V low voltage detector high threshold	—	—	4.4	V
V _{IOLVDM5OK_L}	P	I/O 5 V low voltage detector low threshold	—	3.8	—	V
V _{MLVDDOK_H}	P	Digital supply low voltage detector high	—	—	1.145	V
V _{MLVDDOK_L}	P	Digital supply low voltage detector low	—	1.08	—	V

¹ V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = -40 °C to T_A MAX, unless otherwise specified

3.9 Power up/down sequencing

To prevent an overstress event or a malfunction within and outside the device, the MPC5602P implements the following sequence to ensure each module is started only when all conditions for switching it ON are available:

- A POWER_ON module working on voltage regulator supply controls the correct start-up of the regulator. This is a key module ensuring safe configuration for all voltage regulator functionality when supply is below 1.5 V. Associated POWER_ON (or POR) signal is active low.
- Several low voltage detectors, working on voltage regulator supply monitor the voltage of the critical modules (voltage regulator, I/Os, flash memory and low voltage domain). LVDs are gated low when POWER_ON is active.
- A POWER_OK signal is generated when all critical supplies monitored by the LVD are available. This signal is active high and released to all modules including I/Os, flash memory and 16 MHz RC oscillator needed during power-up phase and reset phase. When POWER_OK is low the associated modules are set into a safe state.

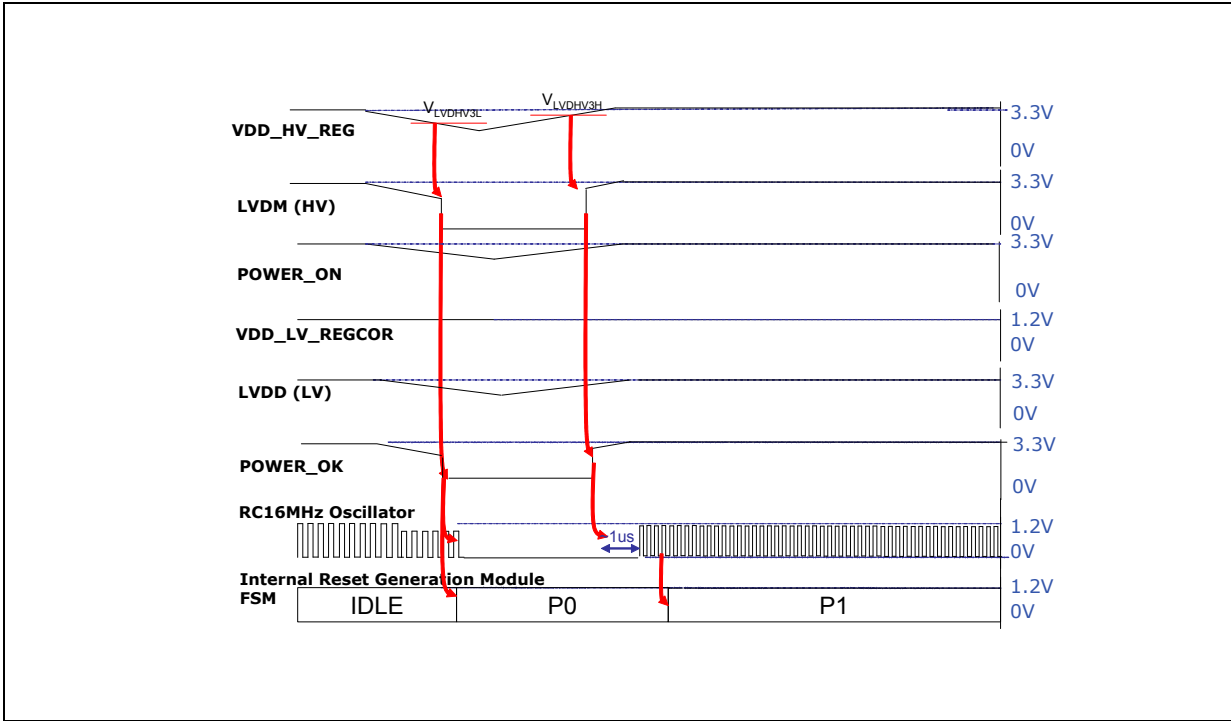


Figure 11. Brown-out typical sequence

3.10 DC electrical characteristics

3.10.1 NVUSRO register

Portions of the device configuration, such as high voltage supply and watchdog enable/disable after reset are controlled via bit values in the non-volatile user options (NVUSRO) register.

For a detailed description of the NVUSRO register, please refer to the device reference manual.

3.10.1.1 NVUSRO[PAD3V5V] field description

The DC electrical characteristics are dependent on the PAD3V5V bit value. Table 16 shows how NVUSRO[PAD3V5V] controls the device configuration.

Table 16. PAD3V5V field description

Value ¹	Description
0	High voltage supply is 5.0 V
1	High voltage supply is 3.3 V

¹ Default manufacturing value before flash initialization is '1' (3.3 V).

3.10.2 DC electrical characteristics (5 V)

Table 17 gives the DC electrical characteristics at 5 V ($4.5 \text{ V} < V_{DD_HV_IOx} < 5.5 \text{ V}$, NVUSRO[PAD3V5V] = 0).

3.15.3 Start-up/Switch-off timings

Table 33. Start-up time/Switch-off time

Symbol	C	Parameter	Conditions ¹	Value			Unit
				Min	Typ	Max	
T _{FLARSTEXIT}	CC	T	Delay for Flash module to exit reset mode	Code flash memory	—	—	125
				Data flash memory	—	—	125
T _{FLALPEXIT}	CC	D	Delay for Flash module to exit low-power mode	Code flash memory	—	—	0.5
T _{FLAPDEXIT}	CC	T	Delay for Flash module to exit power-down mode	Code flash memory	—	—	30
				Data flash memory	—	—	30
T _{FLALPENRY}	CC	D	Delay for Flash module to enter low-power mode	Code flash memory	—	—	0.5

¹ V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = -40 to 125 °C, unless otherwise specified.

3.16 AC specifications

3.16.1 Pad AC specifications

Table 34. Output pin transition times

Symbol		C	Parameter	Conditions ¹		Value			Unit
						Min	Typ	Max	
t _{tr}	CC	D	Output transition time output pin ² SLOW configuration	C _L = 25 pF	V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	50	ns
		T		C _L = 50 pF		—	—	100	
		D		C _L = 100 pF		—	—	125	
		D		C _L = 25 pF	V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	40	
		T		C _L = 50 pF		—	—	50	
		D		C _L = 100 pF		—	—	75	
		D		C _L = 100 pF		—	—	75	
t _{tr}	CC	D	Output transition time output pin ² MEDIUM configuration	C _L = 25 pF	V _{DD} = 5.0 V ± 10%, PAD3V5V = 0 SIUL.PCRx.SRC = 1	—	—	10	ns
		T		C _L = 50 pF		—	—	20	
		D		C _L = 100 pF		—	—	40	
		D		C _L = 25 pF	V _{DD} = 3.3 V ± 10%, PAD3V5V = 1 SIUL.PCRx.SRC = 1	—	—	12	
		T		C _L = 50 pF		—	—	25	
		D		C _L = 100 pF		—	—	40	
		D		C _L = 100 pF		—	—	40	

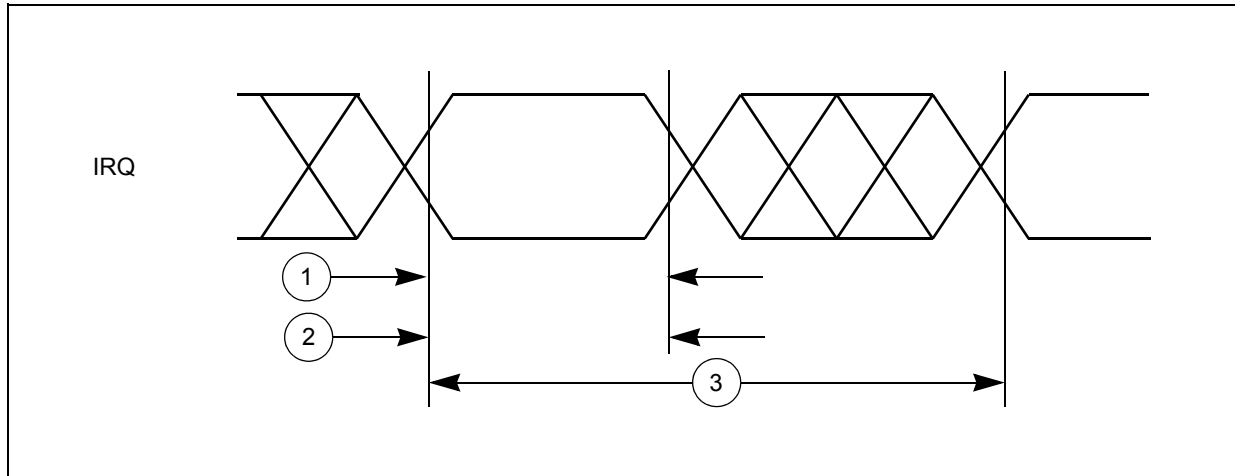


Figure 26. External interrupt timing

3.17.5 DSPI timing

Table 39. DSPI timing¹

No.	Symbol	C	Parameter	Conditions	Value		Unit	
					Min	Max		
1	t _{SCK}	CC	D	DSPI cycle time	Master (MTFE = 0)	60	—	ns
					Slave (MTFE = 0)	60	—	
2	t _{CSC}	CC	D	CS to SCK delay	—	16	—	ns
3	t _{ASC}	CC	D	After SCK delay	—	26	—	ns
4	t _{SDC}	CC	D	SCK duty cycle	—	0.4 * t _{SCK}	0.6 * t _{SCK}	ns
5	t _A	CC	D	Slave access time	SS active to SOUT valid	—	30	ns
6	t _{DIS}	CC	D	Slave SOUT disable time	SS inactive to SOUT high impedance or invalid	—	16	ns
7	t _{PCSC}	CC	D	PCSx to PCSS time	—	13	—	ns
8	t _{PASC}	CC	D	PCSS to PCSx time	—	13	—	ns
9	t _{SUI}	CC	D	Data setup time for inputs	Master (MTFE = 0)	35	—	ns
					Slave	4	—	
					Master (MTFE = 1, CPHA = 0)	35	—	
					Master (MTFE = 1, CPHA = 1)	35	—	
10	t _{HI}	CC	D	Data hold time for inputs	Master (MTFE = 0)	–5	—	ns
					Slave	4	—	
					Master (MTFE = 1, CPHA = 0)	11	—	
					Master (MTFE = 1, CPHA = 1)	–5	—	

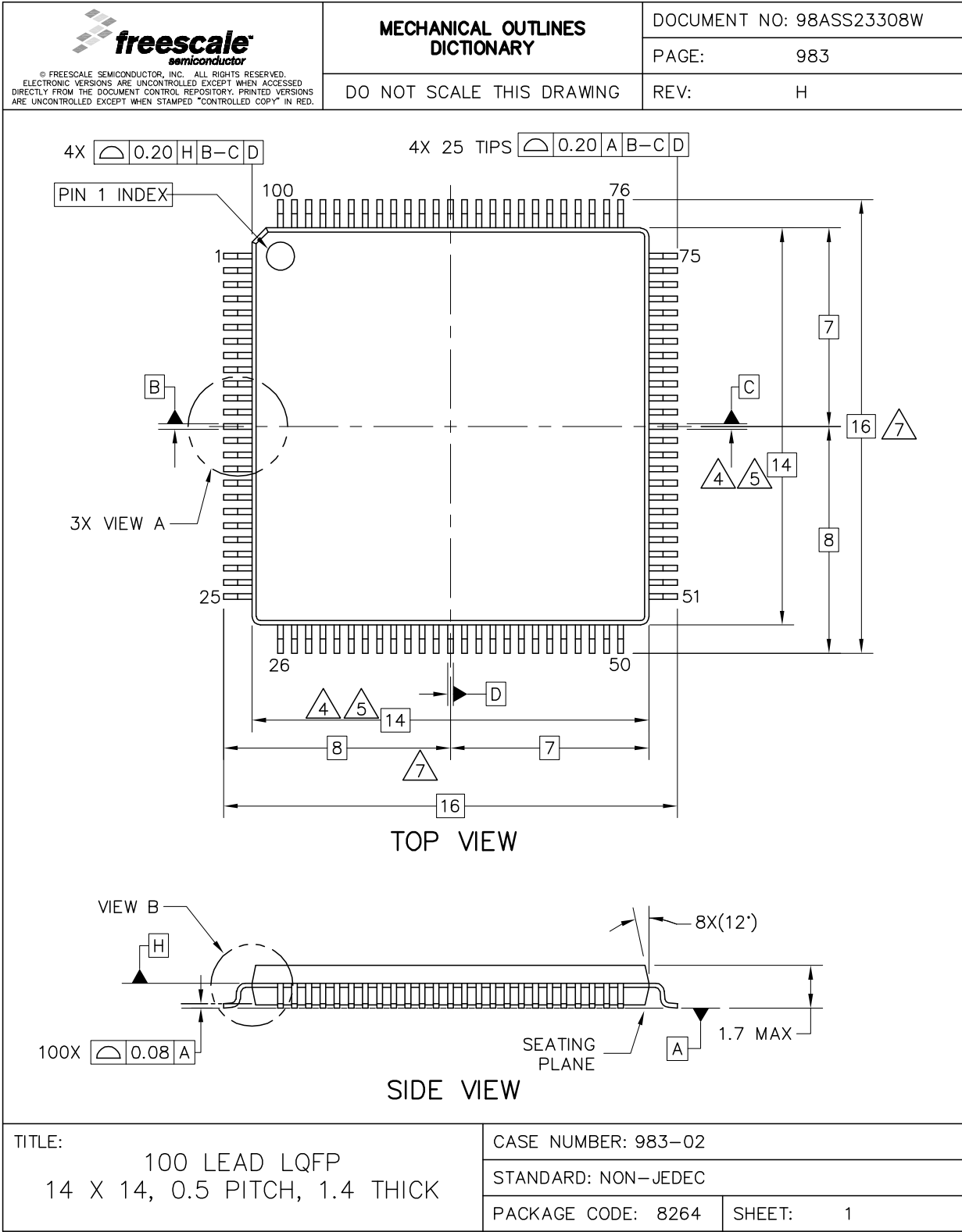


Figure 36. 100 LQFP package mechanical drawing (part 1)

4.1.2 64 LQFP mechanical outline drawing

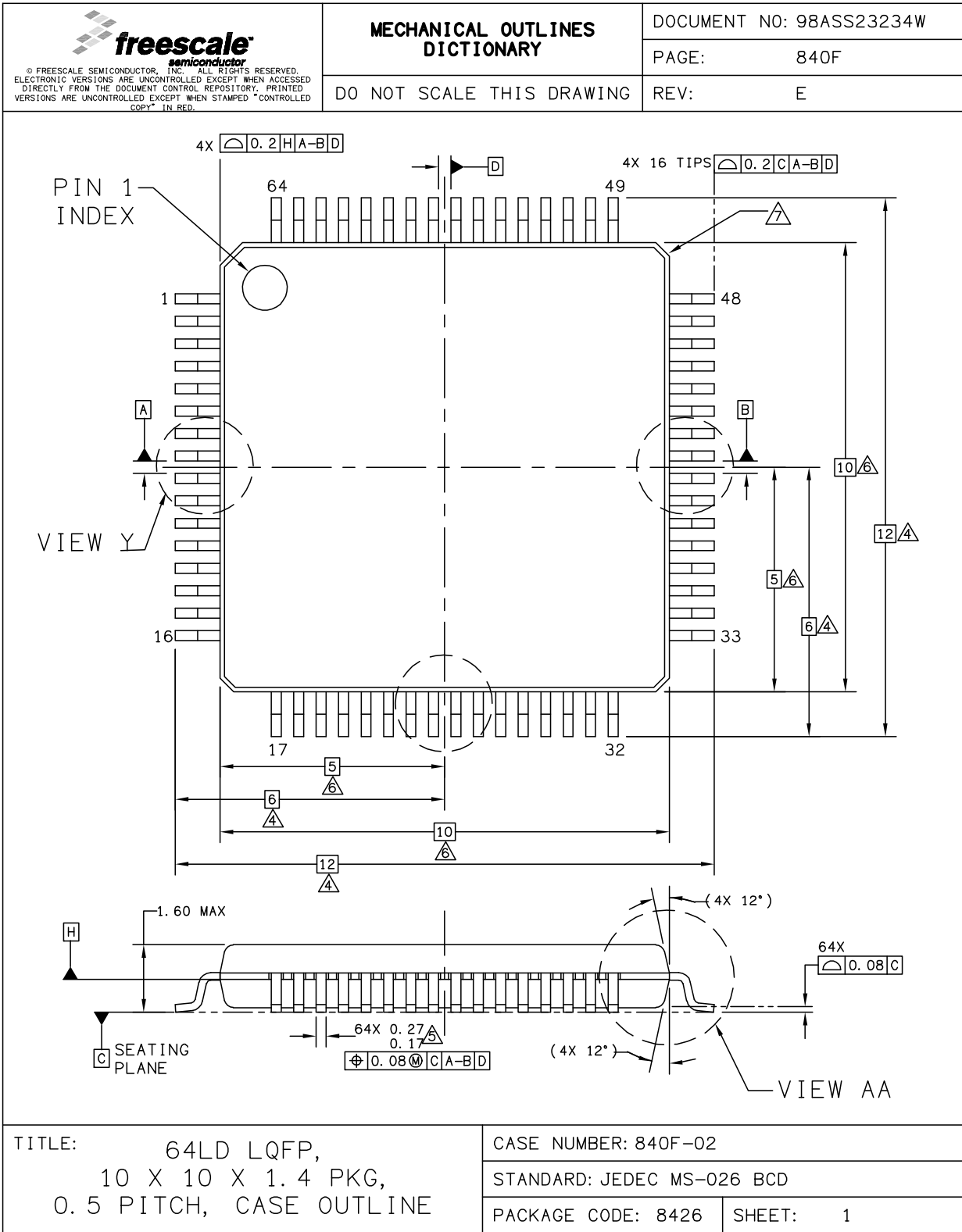


Table 40. Revision history (continued)

Revision	Date	Description of
3 (continued)	16 Dec 2010	<p>"Program and erase specifications" table:</p> <ul style="list-style-type: none"> • $T_{wprogram}$: updated initial max and max values • T_{BKPRG}, 64 KB: updated initial max and max values • added information about "erase time" for Data Flash <p>"Flash module life" table:</p> <ul style="list-style-type: none"> • P/E, 32 KB: added typ value • P/E, 128 KB: added typ value <p>Replaced "Pad AC specifications (5.0 V, NVUSRO[PAD3V5V] = 0)" and "Pad AC specifications (3.3 V, INVUSRO[PAD3V5V] = 1)" tables with "Output pin transition times" table</p> <p>"JTAG pin AC electrical characteristics" table:</p> <ul style="list-style-type: none"> • t_{TDOV}: updated max value • t_{TDOHZ}: added min value and removed max value <p>"Nexus debug port timing" table: removed the rows "t_{MCYC}", "t_{MDOV}", "t_{MSEOV}", and "$t_{EVT OV}$"</p> <p>Updated "External interrupt timing (IRQ pin)" table</p> <p>Updated "FlexCAN timing" table</p> <p>Updated "DSPI timing" table</p> <p>Updated "Ordering information" section</p>

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